Vishay Semiconductors

Hyperfast Rectifier, 30 A FRED Pt®



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PRODUCT SUMMARY						
Package	TO-247AD 3L					
I _{F(AV)}	30 A					
V _R	600 V					
V _F at I _F	1.4 V					
t _{rr} typ.	26 ns					
T _J max.	175 °C					
Diode variation	Single die					

FEATURES

- Low forward voltage drop
- Hyperfast soft recovery time
- 175 °C operating junction temperature
- Designed and qualified according to commercial qualification
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Repetitive peak reverse voltage	V _{RRM}		600	V			
Average rectified forward current	I _{F(AV)}	T _C = 112 °C	30				
Non-repetitive peak surge current	I _{FSM}	$T_C = 25$ °C, $t_p = 8.3$ ms half sine wave; connecting two anode pins	240	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward voltage	N	I _F = 30 A	-	2.0	2.65	V	
	V _F	I _F = 30 A, T _J = 150 °C	-	1.4	1.8		
		V _R = V _R rated	-	0.02	30		
Reverse leakage current I _R		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	300	μA	
Junction capacitance	CT	V _R = 600 V	-	20	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

PI



RoHS COMPLIANT HALOGEN FREE

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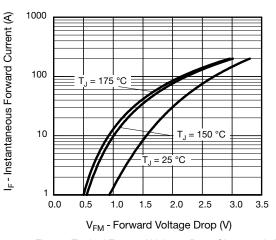
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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$		-	26	-		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	26	-	ns	
		T _J = 125 °C		-	70	-		
Peak recovery current	I _{RRM}	T _J = 25 °C	I _F = 30 A dI _F /dt = 200 A/μs V _R = 200 V	-	3.5	-	A	
		T _J = 125 °C		-	7.6	-		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	50	-	nC	
		T _J = 125 °C]	-	280	-	10	

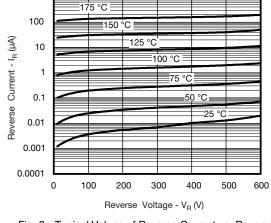
THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	MBOL TEST CONDITIONS		TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Thermal resistance, junction to case	R _{thJC}		-	0.7	1.1	°C/W		
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	70			
Thermal resistance, case to heat sink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-			
Weight			-	5.5	-	g		
Weight			-	0.2	-	oz.		
Mounting torque			1.2 (10)	-	2.4 (20)	kgf · cm (lbf · in)		
Marking device		Case style TO-247AD 3L	APH3006L					

VS-APH3006L-N3

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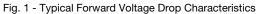
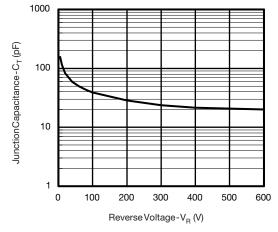
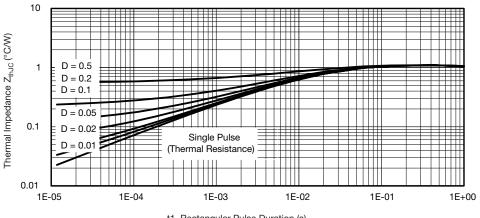


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



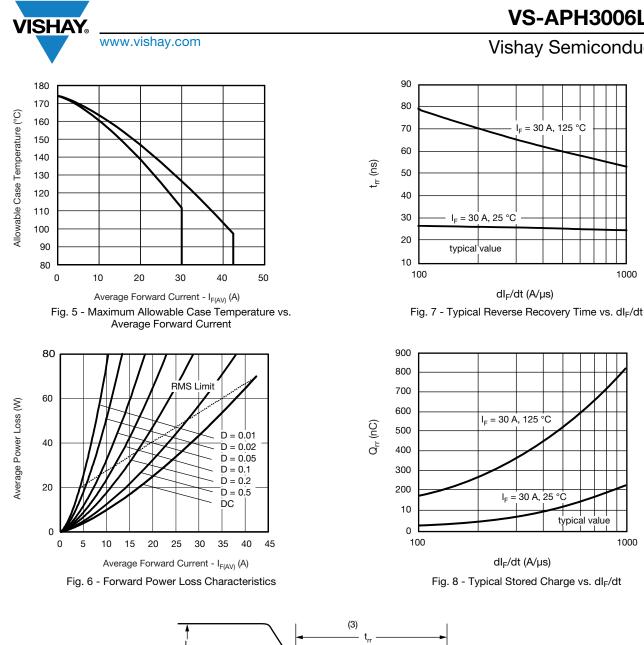
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Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



t1, Rectangular Pulse Duration (s)

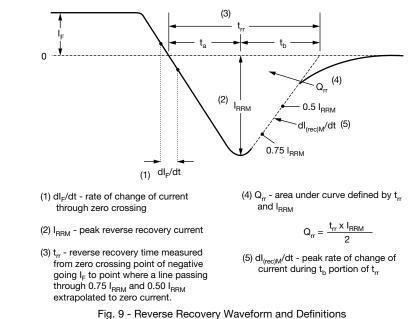
Fig. 4 - Max. Thermal Impedance $Z_{thJC} \mbox{ Characteristics}$



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ORDERING INFORMATION TABLE

Device code	VS-	Α	Р	н	30	06	L	-N3
	1	2	3	4	5	6	7	8
	1 -	Visl	nay Sem	niconduc	ctors pro	oduct		
	2 -	A =	single c	liode				
	3 -	P =	TO-247	,				
	4 -	H =	hyperfa	ast recov	ery time	e		
	5 -	Cur	rent coc	le (30 =	30 A)			
	6 -	Volt	age coo	de (06 =	600 V)			
	7 -	L =	long lea	d				
	8 -			ntal digit				
		-N3	= halog	jen-free,	RoHS-	complia	int, and	totally I

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-APH3006L-N3	25	500	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS							
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626					
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007					



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TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 0.209 A 4.65 5.31 0.183 0.087 A1 2.21 2.59 0.102 A2 1.50 2.49 0.059 0.098 b 0.99 1.40 0.039 0.055 b1 0.99 1.35 0.039 0.053 b2 1.65 2.39 0.065 0.094 b3 1.65 2.34 0.065 0.092 b4 2.59 3.43 0.102 0.135 b5 2.59 3.38 0.102 0.133 с 0.38 0.89 0.015 0.035 c1 0.38 0.84 0.015 0.033 D 19.71 20.70 0.776 0.815 3 D1 13.08 -0.515 4

(2, 2_, 2, 7) (4) Section C - C, D - D, E - E

SYMBOL	MILLIMETERS		INC	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	5 BSC	
ØК	2.	2.54		0.010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51	BSC	0.217	' BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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